

# LOW DROP DUAL POWER OPERATIONAL AMPLIFIERS

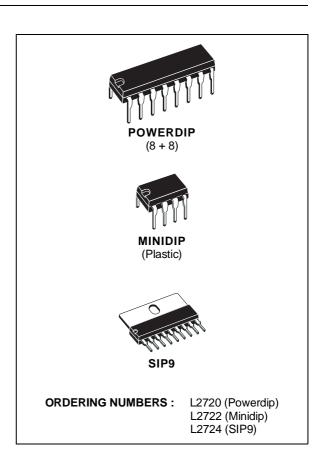
- OUTPUT CURRENT TO 1 A
- OPERATES AT LOW VOLTAGES
- SINGLE OR SPLIT SUPPLY
- LARGE COMMON-MODE AND DIFFEREN-TIAL MODE RANGE
- LOW INPUT OFFSET VOLTAGE
- GROUND COMPATIBLE INPUTS
- LOW SATURATION VOLTAGE
- THERMAL SHUTDOWN
- CLAMP DIODE



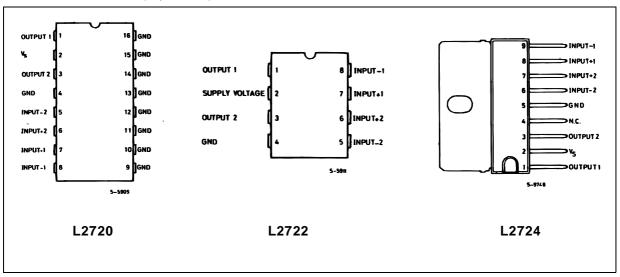
The L2720, L2722 and L2724 are monolithic integrated circuits in powerdip, minidip and SIP-9 packages, intended for use as power operational amplifiers in a wide range of applications including servo amplifiers and power supplies.

They are particularly indicated for driving, inductive loads, as motor and finds applications in compact-disc VCR automotive, etc.

The high gain and high output power capability provide superior performance whatever an operational amplifier/power booster combination is required.

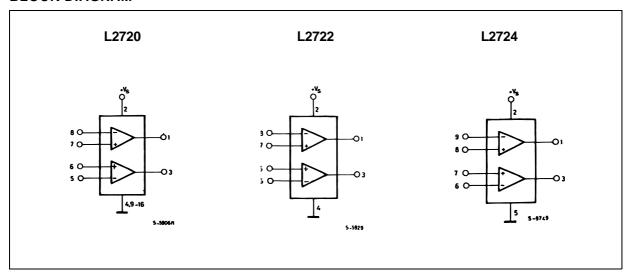


#### PIN CONNECTIONS (top views)

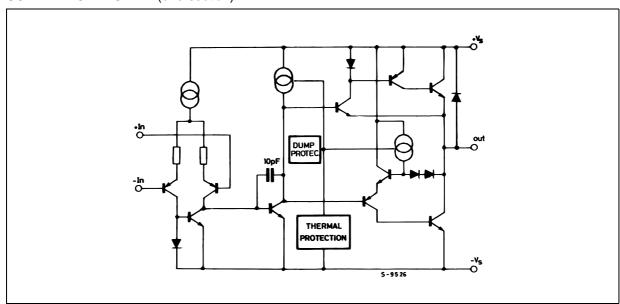


November 1996 1/10

### **BLOCK DIAGRAM**



# SCHEMATIC DIAGRAM (one section)



# **ABSOLUTE MAXIMUM RATINGS**

| Symbol                            | Parameter   | Value        | Unit |
|-----------------------------------|---|--------------|------|
| Vs                                | Supply Voltage  | 28           | V    |
| Vs                                | Peak Supply Voltage (50ms)  | 50           | ٧    |
| $V_{i}$                           | Input Voltage   | Vs           |      |
| $V_{i}$                           | Differential Input Voltage  | ±Vs          |      |
| Ιο                                | DC Output Current   | 1            | Α    |
| $I_p$                             | Peak Output Current (non repetitive)  | 1.5          | Α    |
| P <sub>tot</sub>                  | Power Dissipation at $T_{amb} = 80^{\circ}C$ (L2720), $T_{amb} = 50^{\circ}C$ (L2722) $T_{case} = 75^{\circ}C$ (L2720) $T_{case} = 50^{\circ}C$ (L2724) | 1<br>5<br>10 | W    |
| T <sub>stg</sub> , T <sub>j</sub> | Storage and Junction Temperature  | -40 to 150   | °C   |

### THERMAL DATA

|                        |                                     |      | SIP-9  | Powerdip | Minidip |
|------------------------|-------------------------------------|------|--------|----------|---------|
| R <sub>th j-case</sub> | Thermal Resistance Junction-case    | Max. | 10°C/W | 15°C/W   | 70°C/W  |
| R <sub>th j-amb</sub>  | Thermal Resistance Junction-ambient | Max. | 70°C/W | 70°C/W   | 100°C/W |

### **ELECTRICAL CHARACTERISTICS**

 $V_s = 24V$ ,  $T_{amb} = 25$ °C unless otherwise specified

| Symbol                   | Parameter                                | Test Conditions                                 |  | Min. | Тур.           | Max.     | Unit |
|--------------------------|--|---|--|------|----------------|----------|------|
| Vs                       | Single Supply Voltage                    |   |  | 4    |                | 28       | V    |
| Vs                       | Split Supply Voltage                     |   |  | ± 2  |                | ± 14     | V    |
| Is                       | Quiescent Drain Current                  | $V_0 = \frac{V_s}{2}$                           | V <sub>s</sub> = 24V<br>V <sub>s</sub> = 8V      |      | 10<br>9        | 15<br>15 | mA   |
| I <sub>b</sub>           | Input Bias Current                       |   | V 5 – O V  |      | 0.2            | 1        | μА   |
| Vos                      | Input Offset Voltage                     |   |  |      |                | 10       | mV   |
| I <sub>os</sub>          | Input Offset Current                     |   |  |      |                | 100      | nA   |
| SR                       | Slew Rate                                |   |  |      | 2              |          | V/µs |
| В                        | Gain-bandwidth Product                   |   |  |      | 1.2            |          | MHz  |
| Ri                       | Input Resistance                         |   |  | 500  |                |          | kΩ   |
| Gv                       | O.L. Voltage Gain                        | f = 100Hz<br>f = 1kHz                           |  | 70   | 80<br>60       |          | dB   |
| en                       | Input Noise Voltage                      | B = 22Hz to 22kHz                               |  |      | 10             |          | μV   |
| I <sub>N</sub>           | Input Noise Voltage                      | - D = 22HZ 10 22KHZ                             |  |      | 200            |          | pА   |
| CMR                      | Common Mode Rejection                    | f = 1kHz  |  | 66   | 84             |          | dB   |
| SVR                      | Supply Voltage Rejection                 | $ f = 100Hz \\ R_G = 10k\Omega \\ V_R = 0.5V $  | $V_s = 24V$<br>$V_s = \pm 12V$<br>$V_s = \pm 6V$ | 60   | 70<br>75<br>80 |          | dB   |
| V <sub>DROP</sub> (HIGH) |  | $V_s = \pm 2.5 V \text{ to } \pm 12 V$          | $I_p = 100 \text{mA}$<br>$I_p = 500 \text{mA}$   |      | 0.7<br>1       | 1.5      | V    |
| V <sub>DROP(LOW)</sub>   |  | $V_s = \pm 2.5 V \text{ to } \pm 12 V$          | I <sub>p</sub> = 100mA<br>I <sub>p</sub> = 500mA |      | 0.3<br>0.5     | 1        | V    |
| Cs                       | Channel Separation                       | $ f = 1 KHz \\ R_L = 10 \Omega \\ G_V = 30 dB $ | V <sub>s</sub> = 24V<br>V <sub>s</sub> = 6V      |      | 60<br>60       |          | dB   |
| T <sub>sd</sub>          | Thermal Shutdown Junction<br>Temperature |   |  |      | 145            |          | °C   |

Figure 1: Quiescent Current vs. Supply Voltage

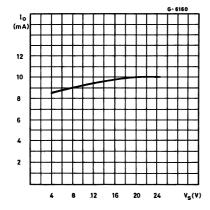
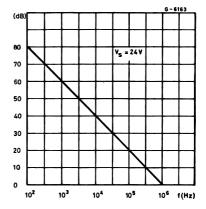


Figure 2: Open Loop Gain vs. Frequency



**Figure 3 :** Common Mode Rejection vs. Frequency

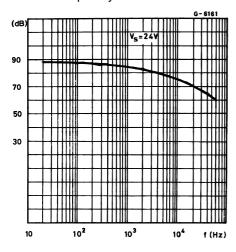
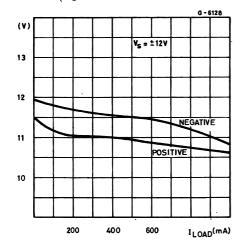


Figure 5 : Output Swing vs. Load Current ( $V_S = \pm 12 \text{ V}$ .



**Figure 7 :** Channel Separation vs. Frequency

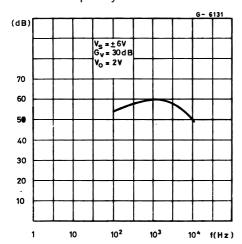
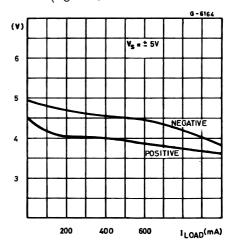
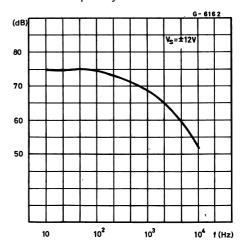


Figure 4 : Output Swing vs. Load Current  $(V_S = \pm 5 V.$ 



**Figure 6 :** Supply Voltage rejection vs. Frequency



#### **APPLICATION SUGGESTION**

In order to avoid possible instability occuring into final stage the usual suggestions for the linear power stages are useful, as for instance :

- layout accuracy;
- A 100nF capacitor connected between supply pins and ground;
- boucherot cell (0.1 to 0.2 μF + 1Ω series) between outputs and ground or across the load.
   With single supply operation, a resistor (1kΩ) between the output and supply pin can be necessary for stability.

Figure 8 : Bidirectional DC Motor Control with  $\mu P$  Compatible Inputs

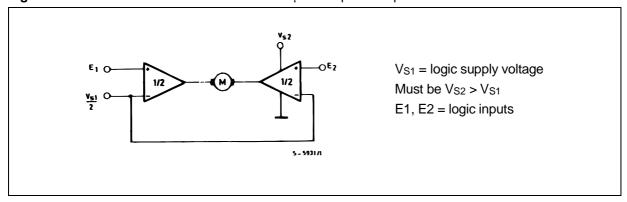


Figure 9: Servocontrol for Compact-disc

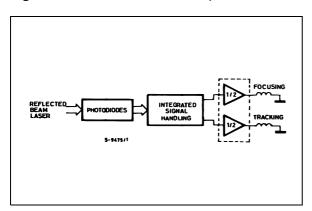


Figure 10 : Capstan Motor Control in Video Recorders

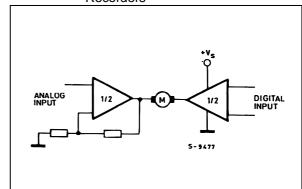


Figure 11: Motor Current Control Circuit

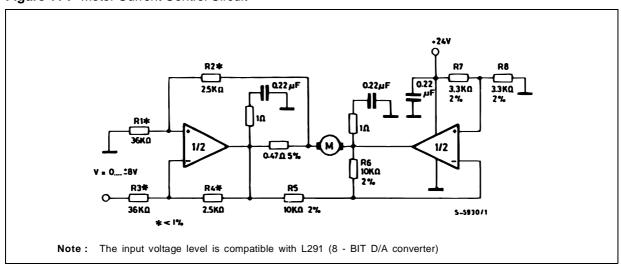


Figure 12: Bidirectional Speed Control of DC Motors

For circuit stability ensure that  $R_X > \frac{2R3 \cdot R1}{RM}$  where  $R_M = \text{internal resistance of motor.}$ 

The voltage available at the terminals of the motor is  $V_M = 2$  ( $V_1 - \frac{V_S}{2}$ ) +  $|R_O|$ .  $I_M$  where  $|R_O| = \frac{2R3 \cdot R1}{R_X}$  and  $I_M$  is the motor current.

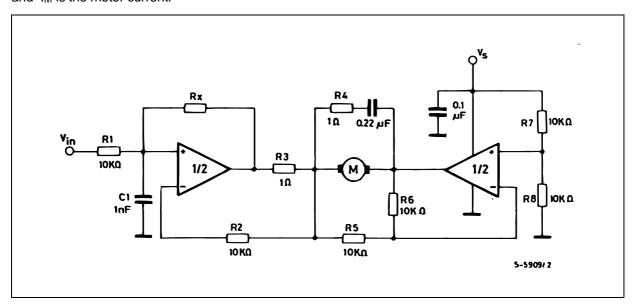
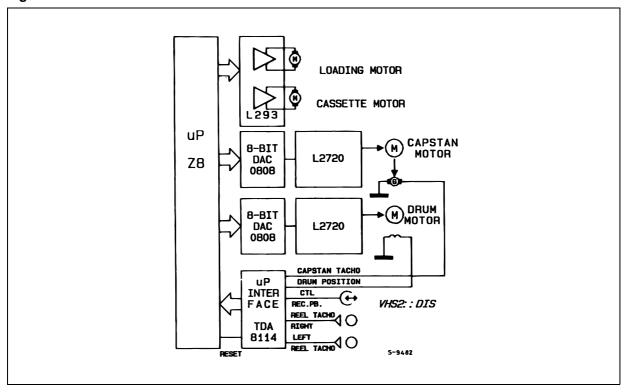
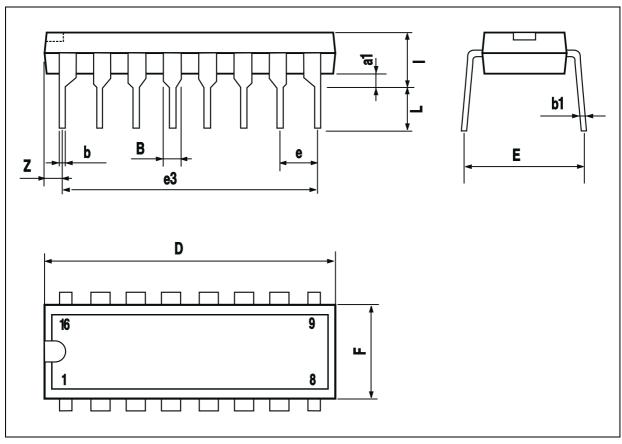


Figure 13: VHS-VCR Motor Control Circuit



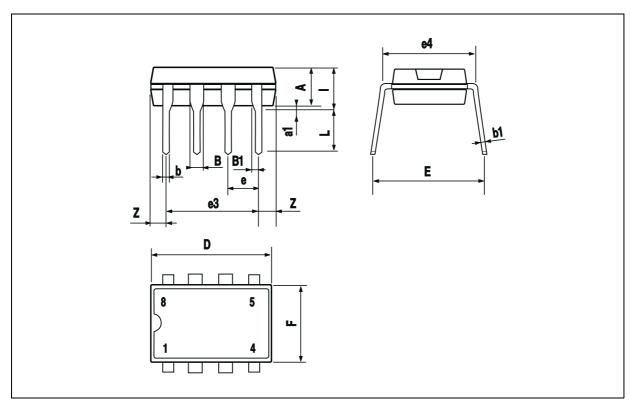
# **POWERDIP 16 PACKAGE MECHANICAL DATA**

| DIM.  | mm   |       |      | inch  |       |       |
|-------|------|-------|------|-------|-------|-------|
| Diwi. | MIN. | TYP.  | MAX. | MIN.  | TYP.  | MAX.  |
| a1    | 0.51 |       |      | 0.020 |       |       |
| В     | 0.85 |       | 1.40 | 0.033 |       | 0.055 |
| b     |      | 0.50  |      |       | 0.020 |       |
| b1    | 0.38 |       | 0.50 | 0.015 |       | 0.020 |
| D     |      |       | 20.0 |       |       | 0.787 |
| Е     |      | 8.80  |      |       | 0.346 |       |
| е     |      | 2.54  |      |       | 0.100 |       |
| e3    |      | 17.78 |      |       | 0.700 |       |
| F     |      |       | 7.10 |       |       | 0.280 |
| l     |      |       | 5.10 |       |       | 0.201 |
| L     |      | 3.30  |      |       | 0.130 |       |
| Z     |      |       | 1.27 |       |       | 0.050 |



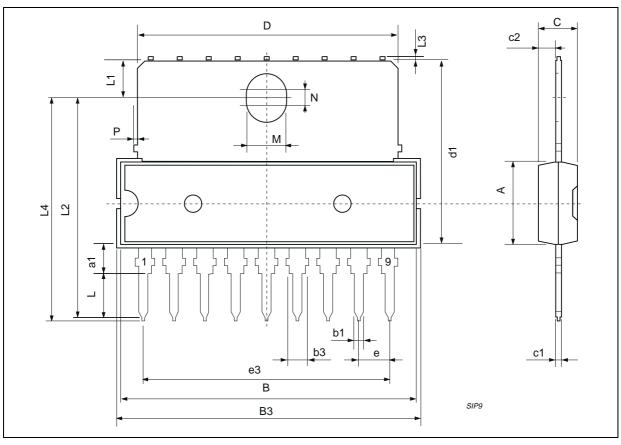
# MINIDIP PACKAGE MECHANICAL DATA

| DIM.   |      | mm   |      | inch  |       |       |
|--------|------|------|------|-------|-------|-------|
| Dilvi. | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| Α      |      | 3.3  |      |       | 0.130 |       |
| a1     | 0.7  |      |      | 0.028 |       |       |
| В      | 1.39 |      | 1.65 | 0.055 |       | 0.065 |
| B1     | 0.91 |      | 1.04 | 0.036 |       | 0.041 |
| b      |      | 0.5  |      |       | 0.020 |       |
| b1     | 0.38 |      | 0.5  | 0.015 |       | 0.020 |
| D      |      |      | 9.8  |       |       | 0.386 |
| Е      |      | 8.8  |      |       | 0.346 |       |
| е      |      | 2.54 |      |       | 0.100 |       |
| e3     |      | 7.62 |      |       | 0.300 |       |
| e4     |      | 7.62 |      |       | 0.300 |       |
| F      |      |      | 7.1  |       |       | 0.280 |
| I      |      |      | 4.8  |       |       | 0.189 |
| L      |      | 3.3  |      |       | 0.130 |       |
| Z      | 0.44 |      | 1.6  | 0.017 |       | 0.063 |



# SIP9 PACKAGE MECHANICAL DATA

| DIM.   | mm   |       |       | inch  |       |       |  |
|--------|------|-------|-------|-------|-------|-------|--|
| DIIVI. | MIN. | TYP.  | MAX.  | MIN.  | TYP.  | MAX.  |  |
| Α      |      |       | 7.1   |       |       | 0.280 |  |
| a1     | 2.7  |       | 3     | 0.106 |       | 0.118 |  |
| В      |      |       | 23    |       |       | 0.90  |  |
| B3     |      |       | 24.8  |       |       | 0.976 |  |
| b1     |      | 0.5   |       |       | 0.020 |       |  |
| b3     | 0.85 |       | 1.6   | 0.033 |       | 0.063 |  |
| С      |      | 3.3   |       |       | 0.130 |       |  |
| c1     |      | 0.43  |       |       | 0.017 |       |  |
| c2     |      | 1.32  |       |       | 0.052 |       |  |
| D      |      |       | 21.2  |       |       | 0.835 |  |
| d1     |      | 14.5  |       |       | 0.571 |       |  |
| е      |      | 2.54  |       |       | 0.100 |       |  |
| e3     |      | 20.32 |       |       | 0.800 |       |  |
| L      | 3.1  |       |       | 0.122 |       |       |  |
| L1     |      | 3     |       |       | 0.118 |       |  |
| L2     |      | 17.6  |       |       | 0.693 |       |  |
| L3     |      |       | 0.25  |       |       | 0.010 |  |
| L4     | 17.4 |       | 17.85 | 0.685 |       | 0,702 |  |
| М      |      | 3.2   |       |       | 0.126 |       |  |
| N      |      | 1     |       |       | 0.039 |       |  |
| Р      |      |       | 0.15  |       |       | 0.006 |  |



Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectronics.

© 1996 SGS-THOMSON Microelectronics – Printed in Italy – All Rights Reserved SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

